

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--|---|------------------|---------|------------------|
| L3 | 518 | 438/478.ccls. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/24 14:21 |
| L4 | 425 | 257/616.ccls. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/24 14:21 |
| S1 | 2 | "20040004271" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/24 10:48 |
| S2 | 1 | digital adj alloy near3 (((silicon si) and (germanium ge)) sige) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 11:44 |
| S3 | 64 | digital adj alloy | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 11:43 |
| S4 | 254 | superlattice near3 (((silicon si) and (germanium ge)) sige) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 13:08 |
| S5 | 237 | superlattice near3 (sige (silicon si) adj (germanium ge)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 11:44 |
| S6 | 216 | S4 and @ad<"20040805" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 13:09 |

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| S7 | 265 | superlattice near3 (((silicon si) near3 (germanium ge)) sige) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 14:14 |
| S8 | 125 | superlattice near3 sige | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 16:13 |
| S9 | 111 | S8 and @ad<"20040805" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 16:13 |
| S10 | 49 | superlattice near3 (silicon adj germanium) and @ad<"20040805" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 14:14 |
| S11 | 35 | S10 not S9 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 15:44 |
| S12 | 9 | S10 and (SOI "silicon on insulator") | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 15:54 |
| S13 | 24 | S9 and (SOI "silicon on insulator") | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 16:01 |
| S14 | 18 | S13 not S12 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 16:02 |

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| S15 | 11 | superlattice near3 si adj ge | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 16:13 |
| S16 | 9 | S15 and @ad<"20040805" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 17:14 |
| S17 | 0 | germanium adj monolayer adj thickness | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 17:14 |
| S18 | 1 | silicon adj monolayer adj thickness | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/21 17:14 |
| S19 | 2 | "20040140531" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/24 09:20 |
| S20 | 255 | SGOI | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/24 10:48 |
| S21 | 208 | S20 and @ad<"20040805" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/24 10:48 |